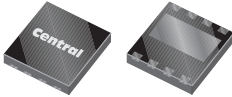


CDFG6558N

**SURFACE MOUNT GaN
N-CHANNEL
POWER FET**

29 AMP, 650 VOLT



Top View Bottom View

DFN8X8 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CDFG6558N is a 650 Volt N-Channel GaN FET designed for high voltage, soft switching applications. This GaN FET combines high voltage capability with low $r_{DS(ON)}$ and low gate charge for optimal efficiency.

MARKING: C6558 8X8 L/C D/C

APPLICATIONS:

- Switch-mode power supplies
- High power chargers
- Electric vehicle inverters

FEATURES:

- High voltage capability
- Low gate charge & $r_{DS(ON)}$
- Fast switching

MAXIMUM RATINGS: ($T_J=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL		UNITS
Drain-Source Voltage	V_{DS}	650	V
Gate-Source Voltage	V_{GS}	-6.0 to +7.0	V
Continuous Drain Current ($T_C=25^\circ\text{C}$)	I_D	29	A
Pulsed Drain Current ($T_C=25^\circ\text{C}$)	I_{DM}	58	A
Power Dissipation ($T_C=25^\circ\text{C}$)	P_D	188	W
Power Dissipation ($T_A=25^\circ\text{C}$)	P_D	1.1	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS: ($T_J=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{GSSF}	$V_{GS}=6.0\text{V}, V_{DS}=0$		163		μA
I_{GSSR}	$V_{GS}=1.0\text{V}, V_{DS}=0$		163		μA
I_{DSS}	$V_{DS}=650\text{V}, V_{GS}=0$		5	65	μA
$V_{gs(th)}$	$V_{GS}=V_{DS}, I_D=30.7\text{mA}$	1.2	1.7	2.5	V
V_{SD}	$V_{GS}=0, I_S=8.0\text{A}$		2.3		V
$r_{DS(ON)}$	$V_{GS}=6.0\text{V}, I_D=8.0\text{A}$		60	80	$\text{m}\Omega$
R_G	$f=5\text{MHz}$; open drain		3		Ω
C_{iss}	$V_{DS}=400\text{V}, V_{GS}=0, f=100\text{kHz}$		225		pF
C_{oss}	$V_{DS}=400\text{V}, V_{GS}=0, f=100\text{kHz}$		70		pF
C_{rss}	$V_{DS}=400\text{V}, V_{GS}=0, f=100\text{kHz}$		0.5		pF
$C_{o(er)}$	$V_{DS}=0$ to 400V, $V_{GS}=0$		105		pF
$C_{o(tr)}$	$V_{DS}=0$ to 400V, $V_{GS}=0$		150		pF
Q_{oss}	$V_{DS}=0$ to 400V, $V_{GS}=0$		60		nC
Q_g	$V_{DS}=400\text{V}, V_{GS}=0\text{V}$ to 6V, $I_D=8\text{A}$		6.2		nC
Q_{gs}	$V_{DS}=400\text{V}, V_{GS}=0\text{V}$ to 6V, $I_D=8\text{A}$		0.5		nC
Q_{gd}	$V_{DS}=400\text{V}, V_{GS}=0\text{V}$ to 6V, $I_D=8\text{A}$		2.2		nC

R1 (9-May 2024)

CDFG6558N

**SURFACE MOUNT GaN
N-CHANNEL
POWER FET**

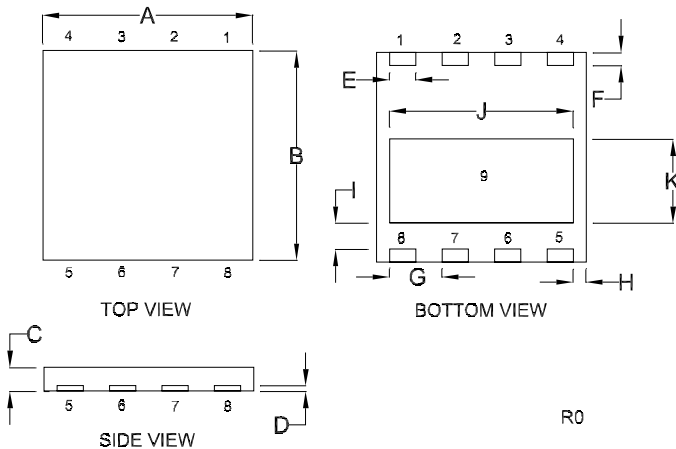
58 AMP, 650 VOLT



ELECTRICAL CHARACTERISTICS - Continued: ($T_J=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	TYP	UNITS
$t_{d(\text{on})}$	$V_{DS}=400\text{V}$, $V_{GS}=6.0\text{V}$, $R_{G(\text{OFF})}=2\Omega$ $R_{G(\text{on})}=10\Omega$, $L=318\mu\text{H}$, $I_D=16\text{A}$	3.0	ns
$t_{d(\text{off})}$	$V_{DS}=400\text{V}$, $V_{GS}=6.0\text{V}$, $R_{G(\text{OFF})}=2\Omega$ $R_{G(\text{on})}=10\Omega$, $L=318\mu\text{H}$, $I_D=16\text{A}$	5.0	ns
t_r	$V_{DS}=400\text{V}$, $V_{GS}=6.0\text{V}$, $R_{G(\text{OFF})}=2\Omega$ $R_{G(\text{on})}=10\Omega$, $L=318\mu\text{H}$, $I_D=16\text{A}$	4.0	ns
t_f	$V_{DS}=400\text{V}$, $V_{GS}=6.0\text{V}$, $R_{G(\text{OFF})}=2\Omega$ $R_{G(\text{on})}=10\Omega$, $L=318\mu\text{H}$, $I_D=16\text{A}$	4.0	ns

DFN8X8 CASE - MECHANICAL OUTLINE



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.307	0.323	7.80	8.20
B	0.307	0.323	7.80	8.20
C	0.031	0.039	0.80	1.00
D	0.006	0.010	0.15	0.25
E	0.037	0.041	0.95	1.05
F	0.018	0.022	0.45	0.55
G	0.071	0.087	1.80	2.20
H	0.018	0.022	0.45	0.55
I	0.037	0.041	0.95	1.05
J	0.268	0.283	6.80	7.20
K	0.120	0.132	3.05	3.35

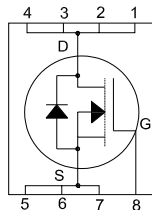
DFN8X8 (REV: R0)

LEAD CODE:

- 1) Drain
- 2) Drain
- 3) Drain
- 4) Drain
- 5) Source
- 6) Source
- 7) Kelvin Source
- 8) Gate
- 9) Source

Pins 5, 6, 7 are common to the pad (pin 9)

MARKING: C6558 8X8 L/C D/C



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